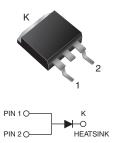


## Vishay General Semiconductor

# **Trench MOS Barrier Schottky Rectifier** for PV Solar Cell Bypass Protection

Ultra Low  $V_F = 0.30 \text{ V}$  at  $I_F = 5 \text{ A}$ 

### TMBS® **TO-263AB**



| PRIMARY CHARACTERISTCS                   |            |  |  |
|--|------------|--|--|
| Package                                  | TO-263AB   |  |  |
| I <sub>F(DC)</sub>                       | 30 A       |  |  |
| V <sub>RRM</sub>                         | 45 V       |  |  |
| I <sub>FSM</sub>                         | 200 A      |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 30 A  | 0.51 V     |  |  |
| T <sub>OP</sub> max. (AC mode)           | 150 °C     |  |  |
| T <sub>J</sub> max. (DC forward current) | 200 °C     |  |  |
| Diode variation                          | Single die |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

· High efficiency operation

HALOGEN FREE Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

- T<sub>J</sub> 200 °C max. in solar bypass application
- Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

#### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

### **MECHANICAL DATA**

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                    |                               |               |      |  |
|--|-------------------------------|---------------|------|--|
| PARAMETER  | SYMBOL                        | VBT3045BP     | UNIT |  |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$                     | 45            | V    |  |
| Maximum DC forward bypassing current (fig. 1)                                      | I <sub>F(DC)</sub> (1)        | 30            | А    |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I <sub>FSM</sub>              | 200           | А    |  |
| Operating junction temperature range (AC mode)                                     | T <sub>OP</sub>               | - 40 to + 150 | °C   |  |
| Junction temperature in DC forward current without reverse bias, $t \le 1\ h$      | T <sub>J</sub> <sup>(2)</sup> | ≤ 200         | °C   |  |

#### **Notes**

- (1) With heatsink
- (2) Meets the requirements of IEC 61215 ed.2 bypass diode thermal test



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                       |                         |                                 |      |      |      |
|---|-----------------------|-------------------------|---------------------------------|------|------|------|
| PARAMETER   | TEST CO               | TEST CONDITIONS         |                                 | TYP. | MAX. | UNIT |
| Instantaneous forward voltage   | I <sub>F</sub> = 5 A  |                         | - V <sub>F</sub> <sup>(1)</sup> | 0.42 | -    | V    |
|   | I <sub>F</sub> = 15 A | T <sub>A</sub> = 25 °C  |                                 | 0.49 | -    |      |
|   | I <sub>F</sub> = 30 A |                         |                                 | 0.58 | 0.70 |      |
|   | I <sub>F</sub> = 5 A  | T <sub>A</sub> = 125 °C |                                 | 0.30 | -    |      |
|   | I <sub>F</sub> = 15 A |                         |                                 | 0.40 | -    |      |
|   | I <sub>F</sub> = 30 A |                         |                                 | 0.51 | 0.60 |      |
| Reverse current   | V <sub>R</sub> = 45 V | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup>   | -    | 2000 | μΑ   |
|   | v <sub>R</sub> = 45 v | T <sub>A</sub> = 125 °C |                                 | 19   | 60   | mA   |

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                |           |      |
|---|----------------|-----------|------|
| PARAMETER   | SYMBOL         | VBT3045BP | UNIT |
| Typical thermal resistance  | $R_{	heta JC}$ | 1.0       | °C/W |

| ORDERING INFORMATION (Example) |                 |                 |              |               |               |
|--------------------------------|-----------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N   | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-263AB                       | VBT3045BP-M3/4W | 1.37            | 4W           | 50/tube       | Tube          |
| TO-263AB                       | VBT3045BP-M3/8W | 1.37            | 8W           | 800/reel      | Tape and reel |

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

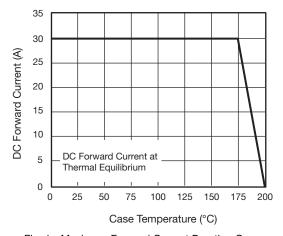


Fig. 1 - Maximum Forward Current Derating Curve

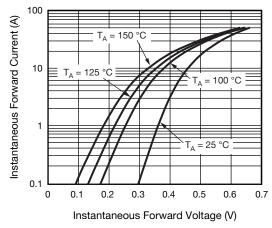
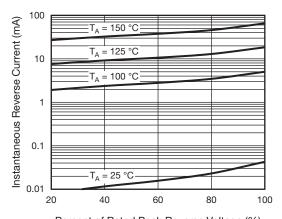


Fig. 2 - Typical Instantaneous Forward Characteristics



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Percent of Rated Peak Reverse Voltage (%) Fig. 3 - Typical Reverse Characteristics

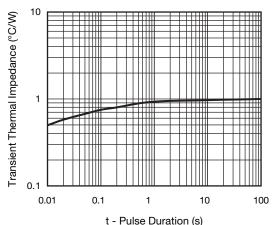


Fig. 5 - Typical Transient Thermal Impedance

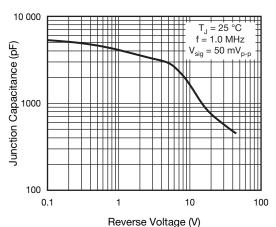


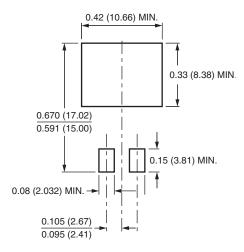
Fig. 4 - Typical Junction Capacitance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) -0 to 0.01 (0 to 0.254) **→** 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

**TO-263AB** 

### **Mounting Pad Layout**





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